

# **BC817-25/SNR Datasheet**



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DiGi Electronics Part Number BC817-25/SNR-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC817-25/SNR

Description TRANS NPN 45V 0.5A TO236AB

**Detailed Description** Bipolar (BJT) Transistor NPN 45 V 500 mA 100MHz 2

50 mW Surface Mount TO-236AB



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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
BC817-25/SNR	Nexperia USA Inc.
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	160 @ 100mA, 1V
Power - Max:	Frequency - Transition:
250 mW	100MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
BC817	

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	



## **BC817** series

## 45 V, 500 mA NPN general-purpose transistors

Rev. 8 — 1 July 2022

**Product data sheet** 

### 1. General description

NPN general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package	PNP complement		
	Nexperia	JEDEC	JEITA	
BC817	SOT23	TO-236AB	-	BC807
BC817-16				BC807-16
BC817-25				BC807-25
BC817-40				BC807-40

## 2. Features and benefits

- High current
- · Three current gain selections

### 3. Applications

· General-purpose switching and amplification

#### 4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base; T <sub>amb</sub> = 25 °C		-	-	45	V
I <sub>C</sub>	collector current	T <sub>amb</sub> = 25 °C		-	-	500	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms; T <sub>amb</sub> = 25 °C		-	-	1	Α
h <sub>FE</sub>	DC current gain		·	'			
	BC817	$V_{CE}$ = 1 V; $I_{C}$ = 100 mA $T_{amb}$ = 25 °C	[1]	100	-	600	
	BC817-16		[1]	100	-	250	
	BC817-25		[1]	160	-	400	
	BC817-40		[1]	250	-	600	

[1] pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 



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**BC817 series** 

45 V, 500 mA NPN general-purpose transistors

## 5. Pinning information

#### Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	E	emitter		5
3	С	collector		B—
				Ė
			1 2	sym123

## 6. Ordering information

#### **Table 4. Ordering information**

Type number	Package	ackage				
	Name	Description	Version			
BC817	TO-236AB	Plastic surface-mounted package; 3 leads	SOT23			
BC817-16						
BC817-25						
BC817-40						

## 7. Marking

#### Table 5. Marking

Type number	Marking code[1]
BC817	6D%
BC817-16	6A%
BC817-25	6B%
BC817-40	6C%

[1] % = placeholder for manufacturing site code

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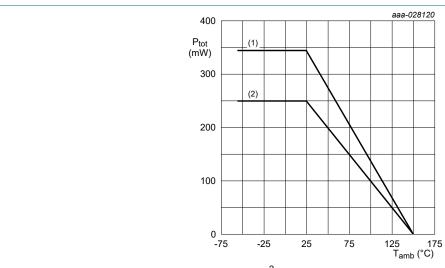
## 8. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter; T <sub>amb</sub> = 25 °C	open emitter; T <sub>amb</sub> = 25 °C		50	V
$V_{CEO}$	collector-emitter voltage	open base; T <sub>amb</sub> = 25 °C		-	45	V
V <sub>EBO</sub>	emitter-base voltage	open collector; T <sub>amb</sub> = 25 °C		-	5	V
I <sub>C</sub>	collector current	T <sub>amb</sub> = 25 °C		-	500	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms; T <sub>amb</sub> = 25 °C	single pulse; t <sub>p</sub> ≤ 1 ms; T <sub>amb</sub> = 25 °C		1	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms; T <sub>amb</sub> = 25 °C	single pulse; t <sub>p</sub> ≤ 1 ms; T <sub>amb</sub> = 25 °C		200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	$T_{amb} \le 25 ^{\circ}C$ [1]		250	mW
			[3]		345	mW
T <sub>j</sub>	junction temperature				150	°C
T <sub>amb</sub>	ambient temperature				150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



- (1) FFR4 PCB, single-sided copper; 1 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper; standard footprint

Fig. 1. Power derating curves

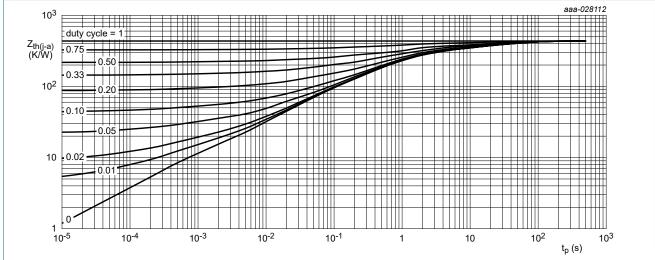
#### 45 V, 500 mA NPN general-purpose transistors

#### 9. Thermal characteristics

**Table 7. Thermal characteristics** 

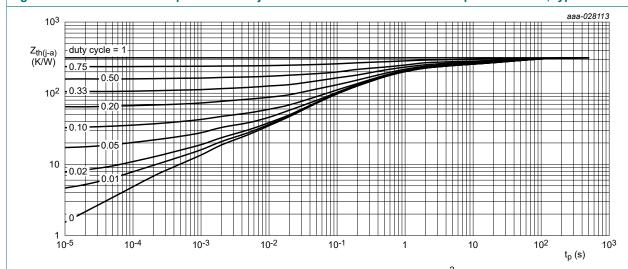
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm<sup>2</sup>.



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 500 mA NPN general-purpose transistors

**BC817 series** 

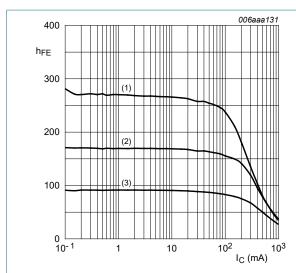
### 10. Characteristics

#### **Table 8. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 10 mA; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		45	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>E</sub> = 100 μA; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		5	-	-	V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	cut-off current	V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
h <sub>FE</sub>	DC current gain				'	'	'
	BC817	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA; T <sub>amb</sub> = 25 °C	[1]	100	-	600	
	BC817-16		[1]	100	-	250	
	BC817-25		[1]	160	-	400	
	BC817-40		[1]	250	-	600	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C	[1]	-	-	700	mV
$V_{BE}$	base-emitter voltage	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1] [2]	-	-	1.2	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	3	-	pF

 $<sup>\</sup>begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$ 

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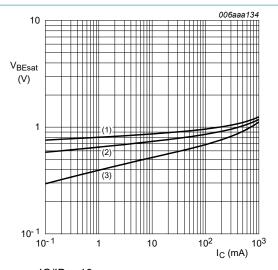
$$V_{CE} = 1 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16: DC current gain as a function of collector current; typical values



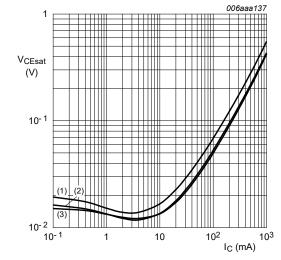
$$IC/IB = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC817-16: Base-emitter saturation voltage as a function of collector current; typical values

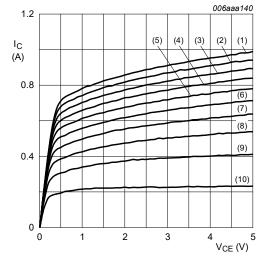


IC/IB = 10

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55$$
 °C

Fig. 6. BC817-16: Collector-emitter saturation voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

 $(1) I_B = 16.0 \text{ mA}$ 

(2)  $I_B = 14.4 \text{ mA}$ 

(3)  $I_B = 12.8 \text{ mA}$ 

 $(4) I_B = 11.2 mA$ 

 $(5) I_B = 9.6 \text{ mA}$ 

(6)  $I_B = 8.0 \text{ mA}$ 

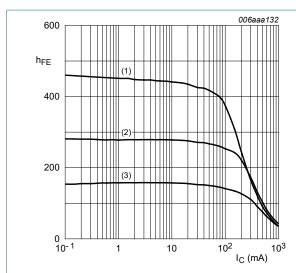
(7)  $I_B = 6.4 \text{ mA}$ 

(8)  $I_B = 4.8 \text{ mA}$ 

(9)  $I_B = 3.2 \text{ mA}$ (10)  $I_B = 1.6 \text{ mA}$ 

Fig. 7. BC817-16: Collector current as a function of collector-emitter voltage; typical values

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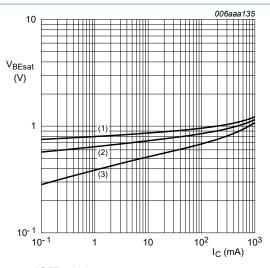
$$V_{CE} = 1 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC817-25: DC current gain as a function of collector current; typical values



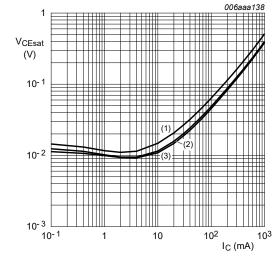
$$IC/IB = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

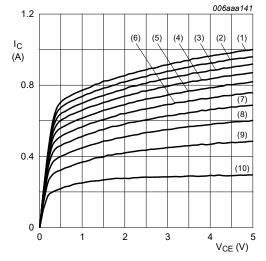
Fig. 9. BC817-25: Base-emitter saturation voltage as a function of collector current; typical values



IC/IB = 10

(3) 
$$T_{amb} = -55$$
 °C

Fig. 10. BC817-25: Collector-emitter saturation voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

 $(1) I_B = 13.0 \text{ mA}$ 

(2)  $I_B = 11.7 \text{ mA}$ 

(3)  $I_B = 10.4 \text{ mA}$ 

(4)  $I_B = 9.1 \text{ mA}$ 

 $(5) I_B = 7.8 \text{ mA}$ 

(6)  $I_B = 6.5 \text{ mA}$ 

(7)  $I_B = 5.2 \text{ mA}$ 

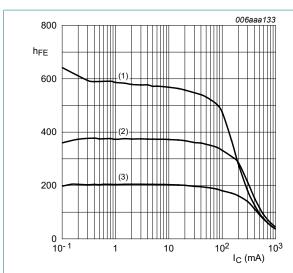
(8)  $I_B = 3.9 \text{ mA}$ 

(9)  $I_B = 2.6 \text{ mA}$ 

 $(10) I_B = 1.3 \text{ mA}$ 

Fig. 11. BC817-25: Collector current as a function of collector-emitter voltage; typical values

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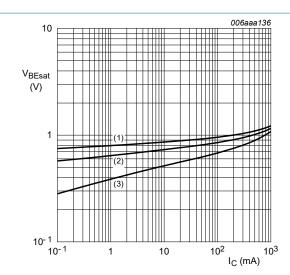
$$V_{CE} = 1 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC817-40: DC current gain as a function of collector current; typical values



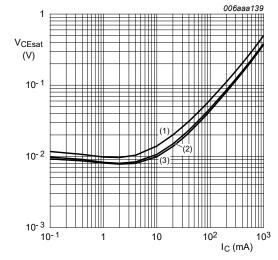
$$IC/IB = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC817-40: Base-emitter saturation voltage as a function of collector current; typical values

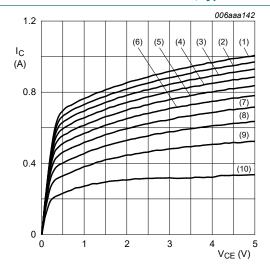


IC/IB = 10

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55$$
 °C

Fig. 14. BC817-40: Collector-emitter saturation voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

 $(1) I_B = 12.0 \text{ mA}$ 

 $(2) I_B = 10.8 \text{ mA}$ 

 $(3) I_B = 9.6 \text{ mA}$ 

(4)  $I_B = 8.4 \text{ mA}$ 

(5)  $I_B = 7.2 \text{ mA}$ 

(6)  $I_B = 6.0 \text{ mA}$ 

 $(7) I_B = 4.8 \text{ mA}$ 

(8)  $I_B = 3.6 \text{ mA}$ 

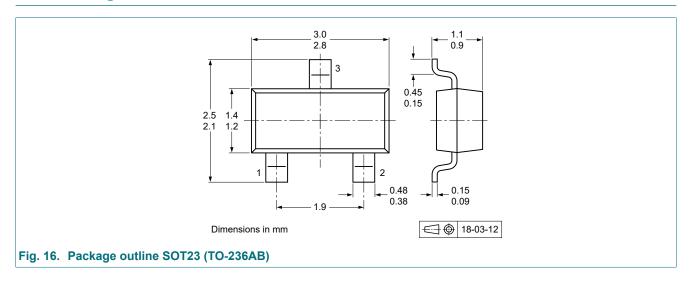
(9)  $I_B = 2.4 \text{ mA}$ 

 $(10) I_B = 1.2 mA$ 

Fig. 15. BC817-40: Collector current as a function of collector-emitter voltage; typical values

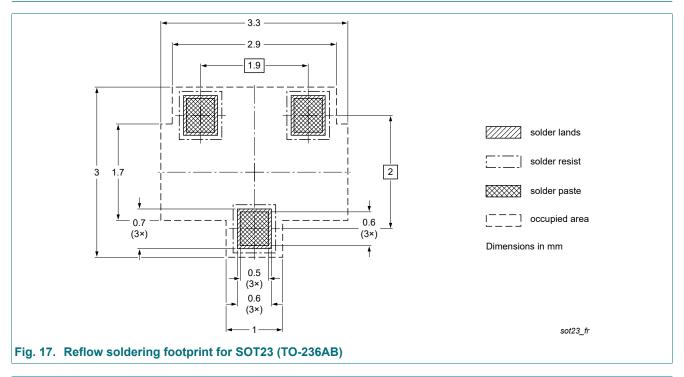
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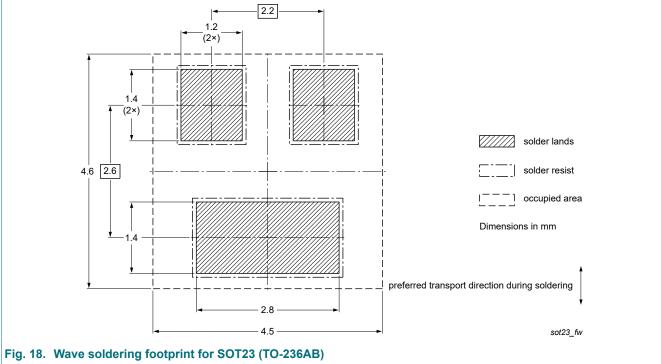
## 11. Package outline



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## 12. Soldering





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## 13. Revision history

#### Table 9. Revision history

Table 5. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
BC817_SER v.8	20220701	Product data sheet	-	BC817_SER v.7			
Modifications:	<ul> <li>Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).</li> </ul>						
BC817_SER v.7	20180615	Product data sheet	-	BC817_BC817W_BC327 v.6			
BC817_BC817W_BC337 v.6	20091117	Product data sheet	-	BC817_BC817W_BC337 v.5			
BC817_BC817W_BC337 v.5	20050221	Product data sheet	CPCN200302007F CPCN200405006F	BC817 v.4 BC817W v.4 BC337 v.3			
BC817 v.4	20040116	Product Specification	-	BC817 v.3			
BC817W_SER v.4	19990518	Product Specification	-	BC817W_SER v.3			
BC337 v.3	19990415	Product Specification	-	BC337_338_CNV v.2			

## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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For more information, please visit: http://www.nexperia.com
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